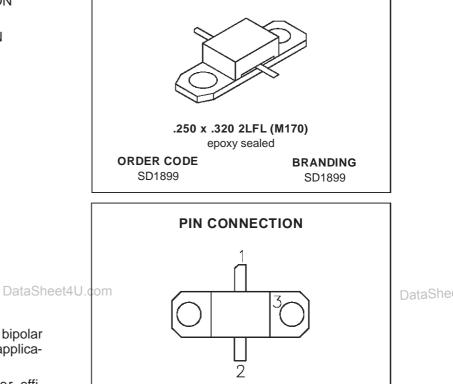


RF & MICROWAVE TRANSISTORS SATELLITE COMMUNICATIONS APPLICATIONS

REFRACTORY/GOLD METALLIZATION

- EFFICIENCY 50% TYPICAL
- POUT = 30 W MIN. WITH 9.3 dB GAIN



1. Collector

2. Emitter

3. Base

DESCRIPTION

The SD1899 is a common base silicon NPN bipolar device optimized for 1.6 GHz SATCOM applications.

SD1899 offers superior gain and collector efficiency, making it an ideal choice for Class C power amplifiers used in portable as well as fixed SAT-COM terminals.

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit		
Vсво	Collector-Base Voltage	45	V		
VCES	Collector-Emitter Voltage 45		V		
V _{EBO}	Emitter-Base Voltage	3.0	V		
Ι _C	Device Current 3.5		A		
P _{DISS}	Power Dissipation (+25°C)	64.8	W		
TJ	Junction Temperature	+200	°C		
T _{STG}	Storage Temperature	– 65 to +150	°C		

THERMAL DATA

R _{TH(j-c)}	R _{TH(j-c)} Junction-Case Thermal Resistance		°C/W

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ELECTRICAL SPECIFICATIONS ($T_{case} = 25^{\circ}C$)

STATIC

Symbol	Test Conditions	Value			Unit		
	Test Conditions		Min.	Тур.	Max.	Onit	
ВV _{CBO}	IC = 8 mA	IE = 0 mA		45	—	—	V
BVCES	IC = 8 mA	VBE = 0 V		45	—	—	V
BV _{EBO}	IE = 8 mA	IC = 0 mA		3.0	—	—	V
Ісво	VCB = 28 V	IE = 0 mA		—	—	2	mA
hFE	VCE = 5 V	IC = 1.6 A		15		150	

DYNAMIC

Symbol	Test Conditions		Value			Unit	
Symbol			Min.	Тур.	Max.	Offic	
Роит	f = 1650 MHz	VCC = 28 V	PIN = 3.5 W	30	32	_	W
ηc	f = 1650 MHz	VCC = 28 V	PIN = 3.5 W	45	50	—	%
PG	f = 1650 MHz	VCC = 28 V		9.3	_	_	dB

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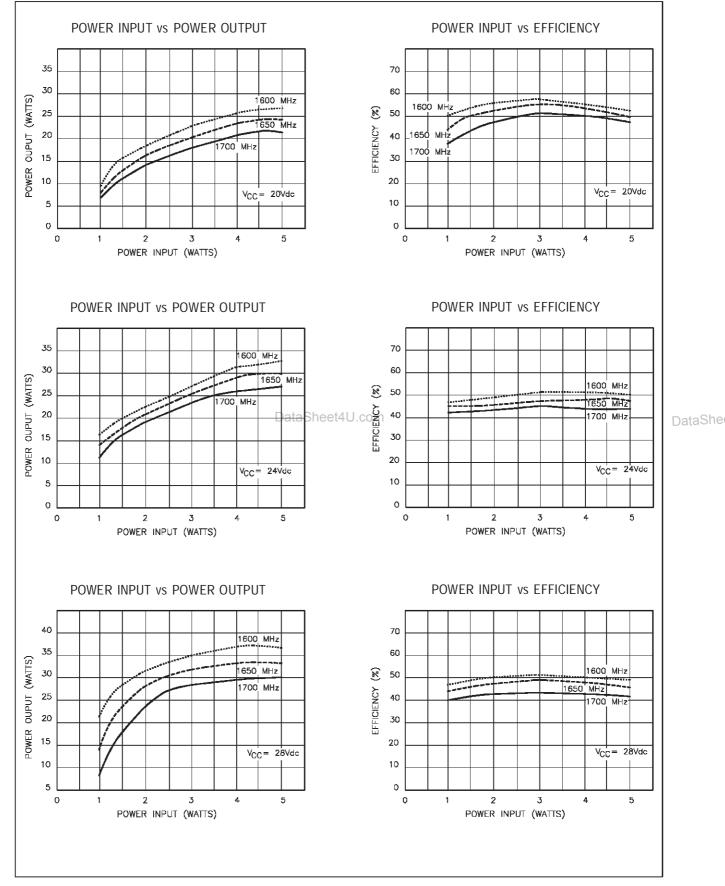
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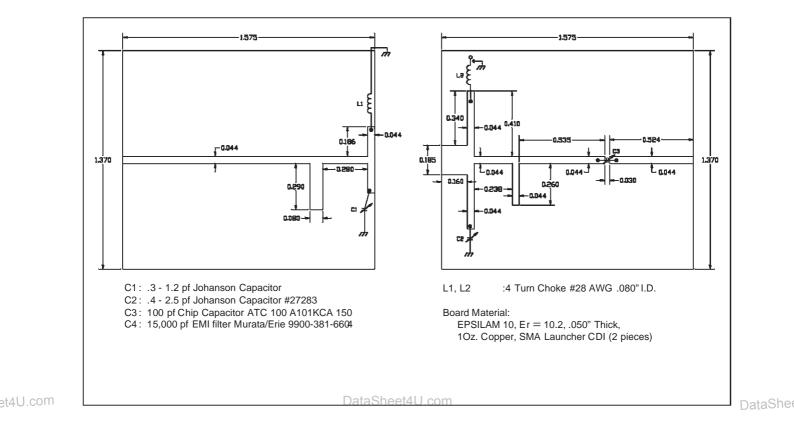
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MIC

TEST CIRCUIT



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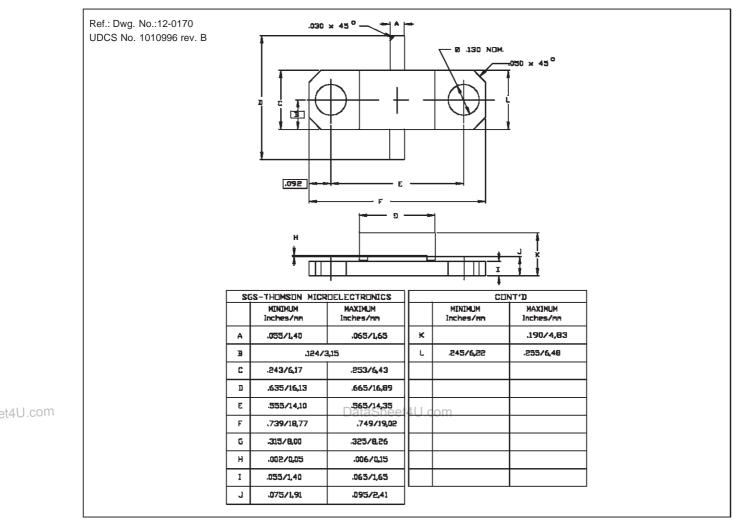
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PACKAGE MECHANICAL DATA



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